

Zhong-Ming Wei

List of Publications by Citations

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

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|--------------------|-------------------------|----------------|-----------------|
| 172 papers | 6,200 citations | 46 h-index | 72 g-index |
| 188 ext. papers | 7,783 ext. citations | 9.1 avg, IF | 6.16 L-index |

| # | Paper | IF | Citations |
|-----|--|------|-----------|
| 172 | Novel and Enhanced Optoelectronic Performances of Multilayer MoS ₂ /WS ₂ Heterostructure Transistors. <i>Advanced Functional Materials</i> , 2014 , 24, 7025-7031 | 15.6 | 320 |
| 171 | Photoresponsive and gas sensing field-effect transistors based on multilayer WS ₂ nanoflakes. <i>Scientific Reports</i> , 2014 , 4, 5209 | 4.9 | 313 |
| 170 | A two-dimensional Fe-doped SnS magnetic semiconductor. <i>Nature Communications</i> , 2017 , 8, 1958 | 17.4 | 214 |
| 169 | Short-Wave Near-Infrared Linear Dichroism of Two-Dimensional Germanium Selenide. <i>Journal of the American Chemical Society</i> , 2017 , 139, 14976-14982 | 16.4 | 191 |
| 168 | Recent Advances in the Functional 2D Photonic and Optoelectronic Devices. <i>Advanced Optical Materials</i> , 2019 , 7, 1801274 | 8.1 | 158 |
| 167 | Electric-Field Tunable Band Offsets in Black Phosphorus and MoS ₂ van der Waals p-n Heterostructure. <i>Journal of Physical Chemistry Letters</i> , 2015 , 6, 2483-8 | 6.4 | 153 |
| 166 | Machine learning in materials science. <i>Information Materials</i> , 2019 , 1, 338-358 | 23.1 | 141 |
| 165 | Direct Vapor Phase Growth and Optoelectronic Application of Large Band Offset SnS ₂ /MoS ₂ Vertical Bilayer Heterostructures with High Lattice Mismatch. <i>Advanced Electronic Materials</i> , 2016 , 2, 1600298 | 6.4 | 128 |
| 164 | Nanowire crystals of a rigid rod conjugated polymer. <i>Journal of the American Chemical Society</i> , 2009 , 131, 17315-20 | 16.4 | 123 |
| 163 | Black Arsenic: A Layered Semiconductor with Extreme In-Plane Anisotropy. <i>Advanced Materials</i> , 2018 , 30, e1800754 | 24 | 109 |
| 162 | A type-II GeSe/SnS heterobilayer with a suitable direct gap, superior optical absorption and broad spectrum for photovoltaic applications. <i>Journal of Materials Chemistry A</i> , 2017 , 5, 13400-13410 | 13 | 108 |
| 161 | Enhanced rectification, transport property and photocurrent generation of multilayer ReSe ₂ /MoS ₂ p-n heterojunctions. <i>Nano Research</i> , 2016 , 9, 507-516 | 10 | 107 |
| 160 | Band-like transport in small-molecule thin films toward high mobility and ultrahigh detectivity phototransistor arrays. <i>Nature Communications</i> , 2019 , 10, 12 | 17.4 | 107 |
| 159 | Perpendicular Optical Reversal of the Linear Dichroism and Polarized Photodetection in 2D GeAs. <i>ACS Nano</i> , 2018 , 12, 12416-12423 | 16.7 | 100 |
| 158 | High-performance single crystalline UV photodetectors of BiGa ₂ O ₃ . <i>Journal of Alloys and Compounds</i> , 2015 , 619, 572-575 | 5.7 | 90 |
| 157 | Thickness-dependent Raman spectra, transport properties and infrared photoresponse of few-layer black phosphorus. <i>Journal of Materials Chemistry C</i> , 2015 , 3, 10974-10980 | 7.1 | 85 |
| 156 | Tunable Polarity Behavior and Self-Driven Photoswitching in p-WSe ₂ /n-WS ₂ Heterojunctions. <i>Small</i> , 2015 , 11, 5430-8 | 11 | 84 |

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| 155 | Toward High-Performance Photodetectors Based on 2D Materials: Strategy on Methods. <i>Small Methods</i> , 2018 , 2, 1700349 | 12.8 | 83 |
| 154 | Graphyne and Its Family: Recent Theoretical Advances. <i>ACS Applied Materials & Interfaces</i> , 2019 , 11, 2692-2706 | 9.5 | 82 |
| 153 | Thickness-Dependent Carrier Transport Characteristics of a New 2D Elemental Semiconductor: Black Arsenic. <i>Advanced Functional Materials</i> , 2018 , 28, 1802581 | 15.6 | 80 |
| 152 | Two-dimensional n-InSe/p-GeSe(SnS) van der Waals heterojunctions: High carrier mobility and broadband performance. <i>Physical Review B</i> , 2018 , 97, | 3.3 | 79 |
| 151 | Recent Advances of 2D Materials in Nonlinear Photonics and Fiber Lasers. <i>Advanced Optical Materials</i> , 2020 , 8, 1901631 | 8.1 | 78 |
| 150 | Flexible photodetectors based on phase dependent PbI ₂ single crystals. <i>Journal of Materials Chemistry C</i> , 2016 , 4, 6492-6499 | 7.1 | 77 |
| 149 | Gas-dependent photoresponse of SnS nanoparticles-based photodetectors. <i>Journal of Materials Chemistry C</i> , 2015 , 3, 1397-1402 | 7.1 | 76 |
| 148 | Large-scale 2D PbI monolayers: experimental realization and their indirect band-gap related properties. <i>Nanoscale</i> , 2017 , 9, 3736-3741 | 7.7 | 75 |
| 147 | Solution-processed ultrathin chemically derived graphene films as soft top contacts for solid-state molecular electronic junctions. <i>Advanced Materials</i> , 2012 , 24, 1333-9 | 24 | 75 |
| 146 | Strain induced piezoelectric effect in black phosphorus and MoS ₂ van der Waals heterostructure. <i>Scientific Reports</i> , 2015 , 5, 16448 | 4.9 | 73 |
| 145 | Ultrathin reduced graphene oxide films as transparent top-contacts for light switchable solid-state molecular junctions. <i>Advanced Materials</i> , 2013 , 25, 4164-70 | 24 | 68 |
| 144 | Van der Waals epitaxial growth of air-stable CrSe nanosheets with thickness-tunable magnetic order. <i>Nature Materials</i> , 2021 , 20, 818-825 | 27 | 68 |
| 143 | Synthesis and transport properties of large-scale alloy Co(0.16)Mo(0.84)S ₂ bilayer nanosheets. <i>ACS Nano</i> , 2015 , 9, 1257-62 | 16.7 | 64 |
| 142 | Composition-tunable 2D SnSe ₂ (1-x)S ₂ x alloys towards efficient bandgap engineering and high performance (opto)electronics. <i>Journal of Materials Chemistry C</i> , 2017 , 5, 84-90 | 7.1 | 64 |
| 141 | Tunable electronic and optical properties of InSe/InTe van der Waals heterostructures toward optoelectronic applications. <i>Journal of Materials Chemistry C</i> , 2018 , 6, 7201-7206 | 7.1 | 63 |
| 140 | Ultrasensitive water-processed monolayer photodetectors. <i>Chemical Science</i> , 2011 , 2, 796 | 9.4 | 60 |
| 139 | Anti-Ambipolar Field-Effect Transistors Based On Few-Layer 2D Transition Metal Dichalcogenides. <i>ACS Applied Materials & Interfaces</i> , 2016 , 8, 15574-81 | 9.5 | 56 |
| 138 | Electronic structure and exciton shifts in Sb-doped MoS ₂ monolayer. <i>Npj 2D Materials and Applications</i> , 2019 , 3, | 8.8 | 56 |

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| 137 | Co-nucleus 1D/2D Heterostructures with Bi ₂ S ₃ Nanowire and MoS ₂ Monolayer: One-Step Growth and Defect-Induced Formation Mechanism. <i>ACS Nano</i> , 2016 , 10, 8938-46 | 16.7 | 55 |
| 136 | Recent advances in low-dimensional semiconductor nanomaterials and their applications in high-performance photodetectors. <i>Informa Materials</i> , 2020 , 2, 291-317 | 23.1 | 54 |
| 135 | Turning a disadvantage into an advantage: synthesizing high-quality organometallic halide perovskite nanosheet arrays for humidity sensors. <i>Journal of Materials Chemistry C</i> , 2017 , 5, 2504-2508 | 7.1 | 52 |
| 134 | High-performance photodetectors based on SbS nanowires: wavelength dependence and wide temperature range utilization. <i>Nanoscale</i> , 2017 , 9, 12364-12371 | 7.7 | 52 |
| 133 | Novel Optical and Electrical Transport Properties in Atomically Thin WSe ₂ /MoS ₂ p/n Heterostructures. <i>Advanced Electronic Materials</i> , 2015 , 1, 1400066 | 6.4 | 52 |
| 132 | Tunable Schottky barrier width and enormously enhanced photoresponsivity in Sb doped SnS ₂ monolayer. <i>Nano Research</i> , 2019 , 12, 463-468 | 10 | 50 |
| 131 | Various Structures of 2D Transition-Metal Dichalcogenides and Their Applications. <i>Small Methods</i> , 2018 , 2, 1800094 | 12.8 | 49 |
| 130 | Wavelength dependent UV-Vis photodetectors from SnS ₂ flakes. <i>RSC Advances</i> , 2016 , 6, 422-427 | 3.7 | 48 |
| 129 | Organic single crystal field-effect transistors based on 6H-pyrrolo[3,2-b:4,5-b']bis[1,4]benzothiazine and its derivatives. <i>Advanced Materials</i> , 2010 , 22, 2458-62 | 24 | 48 |
| 128 | Light induced double band state anti-ambipolar behavior and self-driven photoswitching in p-WSe ₂ /n-SnS ₂ heterostructures. <i>2D Materials</i> , 2017 , 4, 025097 | 5.9 | 46 |
| 127 | Large-Size 2D Bi ₂ S ₃ Nanosheets with Giant Phase Transition Temperature Lowering (120 K) Synthesized by a Novel Method of Super-Cooling Chemical-Vapor-Deposition. <i>Advanced Materials</i> , 2016 , 28, 8271-8276 | 24 | 46 |
| 126 | Tunable Electronic Structures of GeSe Nanosheets and Nanoribbons. <i>Journal of Physical Chemistry C</i> , 2017 , 121, 14373-14379 | 3.8 | 44 |
| 125 | Biphase micro/nanometer sized single crystals of organic semiconductors: Control synthesis and their strong phase dependent optoelectronic properties. <i>Applied Physics Letters</i> , 2010 , 96, 143302 | 3.4 | 44 |
| 124 | Optical and electrical properties of two-dimensional anisotropic materials. <i>Journal of Semiconductors</i> , 2019 , 40, 061001 | 2.3 | 42 |
| 123 | Chemical vapor deposition growth of two-dimensional heterojunctions. <i>Science China: Physics, Mechanics and Astronomy</i> , 2018 , 61, 1 | 3.6 | 42 |
| 122 | Highly polarization sensitive photodetectors based on quasi-1D titanium trisulfide (TiS ₃). <i>Nanotechnology</i> , 2018 , 29, 184002 | 3.4 | 40 |
| 121 | Synthesis, experimental and theoretical characterization, and field-effect transistor properties of a new class of dibenzothiophene derivatives: From linear to cyclic architectures. <i>Journal of Materials Chemistry</i> , 2012 , 22, 1313-1325 | | 40 |
| 120 | Spin-Valve Effect in FeGeTe/MoS ₂ /FeGeTe van der Waals Heterostructures. <i>ACS Applied Materials & Interfaces</i> , 2020 , 12, 43921-43926 | 9.5 | 39 |

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| 119 | Type-II InSe/MoSe ₂ (WSe ₂) van der Waals heterostructures: vertical strain and electric field effects. <i>Journal of Materials Chemistry C</i> , 2018 , 6, 10010-10019 | 7.1 | 38 |
| 118 | Versatile Crystal Structures and (Opto)electronic Applications of the 2D Metal Mono-, Di-, and Tri-Chalcogenide Nanosheets. <i>Advanced Functional Materials</i> , 2019 , 29, 1900040 | 15.6 | 37 |
| 117 | Role of redox centre in charge transport investigated by novel self-assembled conjugated polymer molecular junctions. <i>Nature Communications</i> , 2015 , 6, 7478 | 17.4 | 37 |
| 116 | Tetrathia[22]annulene[2,1,2,1]: physical properties, crystal structure and application in organic field-effect transistors. <i>Journal of Materials Chemistry</i> , 2007 , 17, 4377 | | 37 |
| 115 | Saturable absorption properties and femtosecond mode-locking application of titanium trisulfide. <i>Applied Physics Letters</i> , 2020 , 116, 061901 | 3.4 | 36 |
| 114 | Direct Wide Bandgap 2D GeSe ₂ Monolayer toward Anisotropic UV Photodetection. <i>Advanced Optical Materials</i> , 2019 , 7, 1900622 | 8.1 | 36 |
| 113 | From MoS ₂ Microspheres to HMoO ₃ Nanoplates: Growth Mechanism and Photocatalytic Activities. <i>European Journal of Inorganic Chemistry</i> , 2014 , 2014, 3245-3251 | 2.3 | 36 |
| 112 | Thickness-Dependent Ultrafast Photonics of SnS ₂ Nanolayers for Optimizing Fiber Lasers. <i>ACS Applied Nano Materials</i> , 2019 , 2, 2697-2705 | 5.6 | 35 |
| 111 | Relieving the Photosensitivity of Organic Field-Effect Transistors. <i>Advanced Materials</i> , 2020 , 32, e1906122 | 4.4 | 34 |
| 110 | Molecular junctions based on SAMs of cruciform oligo(phenylene ethynylene)s. <i>Langmuir</i> , 2012 , 28, 4016-4023 | 4.23 | 33 |
| 109 | Highly anisotropic solar-blind UV photodetector based on large-size two-dimensional HMoO ₃ atomic crystals. <i>2D Materials</i> , 2018 , 5, 035033 | 5.9 | 32 |
| 108 | Tunable Schottky Barrier at MoSe ₂ /Metal Interfaces with a Buffer Layer. <i>Journal of Physical Chemistry C</i> , 2017 , 121, 9305-9311 | 3.8 | 31 |
| 107 | Langmuir-Blodgett monolayer as an efficient p-conducting channel of ambipolar organic transistors and a template for n-type molecular alignment. <i>Langmuir</i> , 2009 , 25, 3349-51 | 4 | 31 |
| 106 | Type-I Transition Metal Dichalcogenides Lateral Homo Junctions: Layer Thickness and External Electric Field Effects. <i>Small</i> , 2018 , 14, e1800365 | 11 | 30 |
| 105 | High-Performance Langmuir-Blodgett Monolayer Transistors with High Responsivity. <i>Angewandte Chemie</i> , 2010 , 122, 6463-6467 | 3.6 | 30 |
| 104 | Highly Polarized Photoelectrical Response in vdW ZrS ₃ Nanoribbons. <i>Advanced Electronic Materials</i> , 2019 , 5, 1900419 | 6.4 | 29 |
| 103 | 6H-Pyrrolo[3,2-b:4,5-b']bis[1,4]benzothiazines: facilely synthesized semiconductors for organic field-effect transistors. <i>Journal of Materials Chemistry</i> , 2008 , 18, 4814 | | 27 |
| 102 | Inkjet-Printed Organic Electrodes for Bottom-Contact Organic Field-Effect Transistors. <i>Advanced Functional Materials</i> , 2011 , 21, 786-791 | 15.6 | 26 |

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| 101 | Blending induced stack-ordering and performance improvement in a solution-processed n-type organic field-effect transistor. <i>Journal of Materials Chemistry</i> , 2010 , 20, 1203-1207 | | 26 |
| 100 | Large tunneling magnetoresistance in magnetic tunneling junctions based on two-dimensional CrX (X = Br, I) monolayers. <i>Nanoscale</i> , 2018 , 10, 22196-22202 | 7.7 | 26 |
| 99 | Low temperature electrical transport and photoresponsive properties of H-doped MoO ₃ nanosheets. <i>Journal of Materials Chemistry C</i> , 2014 , 2, 1034-1040 | 7.1 | 25 |
| 98 | Gate-Tunable Ultrahigh Photoresponsivity of 2D Heterostructures Based on Few Layer MoS ₂ and Solution-Processed rGO. <i>Advanced Electronic Materials</i> , 2015 , 1, 1500267 | 6.4 | 25 |
| 97 | Molecular Heterojunctions of Oligo(phenylene ethynylene)s with Linear to Cruciform Framework. <i>Advanced Functional Materials</i> , 2015 , 25, 1700-1708 | 15.6 | 25 |
| 96 | Electrostatic gating dependent multiple-band alignments in a high-temperature ferromagnetic Mg(OH) ₂ /VS ₂ heterobilayer. <i>Physical Review B</i> , 2017 , 95, | 3.3 | 24 |
| 95 | Triazatriangulene as binding group for molecular electronics. <i>Langmuir</i> , 2014 , 30, 14868-76 | 4 | 24 |
| 94 | Development of organic field-effect properties by introducing aryl-acetylene into benzodithiophene. <i>Journal of Materials Chemistry</i> , 2010 , 20, 10931 | | 24 |
| 93 | Gate-tunable diode-like current rectification and ambipolar transport in multilayer van der Waals ReSe/WS p-n heterojunctions. <i>Physical Chemistry Chemical Physics</i> , 2016 , 18, 27750-27753 | 3.6 | 23 |
| 92 | An Efficient and Low-Cost Photolithographic-Pattern-Transfer Technique to Fabricate Electrode Arrays for Micro-/Nanoelectronics. <i>Advanced Materials Technologies</i> , 2016 , 1, 1600001 | 6.8 | 23 |
| 91 | Electric field induced electronic properties modification of ZrS ₂ /HfS ₂ van der Waals heterostructure. <i>RSC Advances</i> , 2017 , 7, 14625-14630 | 3.7 | 22 |
| 90 | Mixed-Valence-Driven Quasi-1D SnIISnIVS ₃ with Highly Polarization-Sensitive UV/Vis/NIR Photoresponse. <i>Advanced Functional Materials</i> , 2019 , 29, 1904416 | 15.6 | 22 |
| 89 | Langmuir-Blodgett monolayer transistors of copper phthalocyanine. <i>Applied Physics Letters</i> , 2009 , 95, 033304 | 3.4 | 21 |
| 88 | Type-I Ca(OH) ₂ /EMoTe ₂ vdW heterostructure for ultraviolet optoelectronic device applications: electric field effects. <i>Journal of Materials Chemistry C</i> , 2017 , 5, 12629-12634 | 7.1 | 20 |
| 87 | Role of defects in enhanced Fermi level pinning at interfaces between metals and transition metal dichalcogenides. <i>Physical Review B</i> , 2017 , 96, | 3.3 | 20 |
| 86 | Electric field-tunable electronic structures of 2D alkaline-earth metal hydroxide/graphene heterostructures. <i>Journal of Materials Chemistry C</i> , 2017 , 5, 7230-7235 | 7.1 | 20 |
| 85 | The Coulomb interaction in van der Waals heterostructures. <i>Science China: Physics, Mechanics and Astronomy</i> , 2019 , 62, 1 | 3.6 | 19 |
| 84 | Symmetry-Reduction Enhanced Polarization-Sensitive Photodetection in Core-Shell SbI/SbO van der Waals Heterostructure. <i>Small</i> , 2020 , 16, e1907172 | 11 | 18 |

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| 83 | Ferroelectric-tuned van der Waals heterojunction with band alignment evolution. <i>Nature Communications</i> , 2021 , 12, 4030 | 17.4 | 18 |
| 82 | Effectively modulating thermal activated charge transport in organic semiconductors by precise potential barrier engineering. <i>Nature Communications</i> , 2021 , 12, 21 | 17.4 | 18 |
| 81 | Abnormal low-temperature behavior of a continuous photocurrent in Bi ₂ S ₃ nanowires. <i>Journal of Materials Chemistry C</i> , 2013 , 1, 5866 | 7.1 | 17 |
| 80 | Effect of electrical contact on the performance of Bi ₂ S ₃ single nanowire photodetectors. <i>ChemPhysChem</i> , 2014 , 15, 2510-6 | 3.2 | 17 |
| 79 | Air-stable ambipolar organic field-effect transistor based on a novel bi-channel structure. <i>Journal of Materials Chemistry</i> , 2008 , 18, 2420 | | 17 |
| 78 | Nonvolatile memristor based on heterostructure of 2D room-temperature ferroelectric Hn ₂ Se ₃ and WSe ₂ . <i>Science China Information Sciences</i> , 2019 , 62, 1 | 3.4 | 16 |
| 77 | Iron-doping induced multiferroic in two-dimensional In ₂ Se ₃ . <i>Science China Materials</i> , 2020 , 63, 421-428 | 7.1 | 16 |
| 76 | Low-Noise Dual-Band Polarimetric Image Sensor Based on 1D Bi ₂ S ₃ Nanowire. <i>Advanced Science</i> , 2021 , 8, e2100075 | 13.6 | 16 |
| 75 | Multistate Logic Inverter Based on Black Phosphorus/SnSeS Heterostructure. <i>Advanced Electronic Materials</i> , 2019 , 5, 1800416 | 6.4 | 16 |
| 74 | Direct Polarimetric Image Sensor and Wide Spectral Response Based on Quasi-1D Sb ₂ S ₃ Nanowire. <i>Advanced Functional Materials</i> , 2021 , 31, 2006601 | 15.6 | 16 |
| 73 | Improving the field-effect performance of Bi ₂ S ₃ single nanowires by an asymmetric device fabrication. <i>ChemPhysChem</i> , 2015 , 16, 99-103 | 3.2 | 15 |
| 72 | Perseverance of direct bandgap in multilayer 2D Pb _{1-x} Sn _x under an experimental strain up to 7.69%. <i>2D Materials</i> , 2019 , 6, 025014 | 5.9 | 14 |
| 71 | Non-layered ZnSb nanoplates for room temperature infrared polarized photodetectors. <i>Journal of Materials Chemistry C</i> , 2020 , 8, 6388-6395 | 7.1 | 14 |
| 70 | In-Plane Optical and Electrical Anisotropy of 2D Black Arsenic. <i>ACS Nano</i> , 2021 , 15, 1701-1709 | 16.7 | 14 |
| 69 | Cross-Substitution Promoted Ultrawide Bandgap up to 4.5 eV in a 2D Semiconductor: Gallium Thiophosphate. <i>Advanced Materials</i> , 2021 , 33, e2008761 | 24 | 13 |
| 68 | Reversible Half Wave Rectifier Based on 2D InSe/GeSe Heterostructure with Near-Broken Band Alignment. <i>Advanced Science</i> , 2021 , 8, 1903252 | 13.6 | 13 |
| 67 | Two-dimensional X ₂ Se ₂ (X = Mn, V) based magnetic tunneling junctions with high Curie temperature. <i>Chinese Physics B</i> , 2019 , 28, 107504 | 1.2 | 12 |
| 66 | From negative to positive magnetoresistance in the intrinsic magnetic topological insulator MnBi ₂ Te ₄ . <i>Physical Review B</i> , 2020 , 101, | 3.3 | 12 |

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| 65 | Growth of two-dimensional materials on hexagonal boron nitride (h-BN). <i>Nanotechnology</i> , 2019 , 30, 034003 | 11 |
| 64 | Ultra-sensitive humidity sensors based on ZnSb ₂ O ₄ nanoparticles. <i>RSC Advances</i> , 2015 , 5, 2429-2433 | 3.7 10 |
| 63 | Oxygen-induced abnormal photoelectric behavior of a MoO ₃ /graphene heterocomposite. <i>RSC Advances</i> , 2014 , 4, 49873-49878 | 3.7 10 |
| 62 | Polarization Sensitive Solar-Blind Ultraviolet Photodetectors Based on Ultrawide Bandgap KNb ₃ O ₈ Nanobelt with Fringe-Like Atomic Lattice. <i>Advanced Functional Materials</i> , 2011 , 2111673 | 15.6 10 |
| 61 | Integrated polarization-sensitive amplification system for digital information transmission. <i>Nature Communications</i> , 2021 , 12, 6476 | 17.4 10 |
| 60 | Intercalation of Two-dimensional Layered Materials. <i>Chemical Research in Chinese Universities</i> , 2020 , 36, 584-596 | 2.2 10 |
| 59 | Flexible Sensors Based on Organic-Inorganic Hybrid Materials. <i>Advanced Materials Technologies</i> , 2021 , 6, 2000889 | 6.8 10 |
| 58 | Quasiparticle Band Structure and Optical Properties of the Janus Monolayer and Bilayer SnSSe. <i>Journal of Physical Chemistry C</i> , 2020 , 124, 23832-23838 | 3.8 9 |
| 57 | The More, the Better: Recent Advances in Construction of 2D Multi-Heterostructures. <i>Advanced Functional Materials</i> , 2021 , 31, 2102049 | 15.6 9 |
| 56 | Extrinsic Photoconduction Induced Short-Wavelength Infrared Photodetectors Based on Ge-Based Chalcogenides. <i>Small</i> , 2021 , 17, e2006765 | 11 9 |
| 55 | Tunable electric properties of bilayer InSe with different interlayer distances and external electric field. <i>Semiconductor Science and Technology</i> , 2018 , 33, 034002 | 1.8 8 |
| 54 | Polarimetric Image Sensor and Fermi Level Shifting Induced Multichannel Transition Based on 2D PdPS. <i>Advanced Materials</i> , 2021 , e2107206 | 24 8 |
| 53 | Visible Phototransistors Based on Vertical Nanolayered Heterostructures of SnS/SnS ₂ p/n and SnSe ₂ /SnS ₂ n/p Nanoflakes. <i>ACS Applied Nano Materials</i> , 2020 , 3, 6847-6854 | 5.6 7 |
| 52 | p-MoS/n-InSe van der Waals heterojunctions and their applications in all-2D optoelectronic devices.. <i>RSC Advances</i> , 2019 , 9, 35039-35044 | 3.7 7 |
| 51 | Strong Anisotropy and Piezo-Phototronic Effect in SnO ₂ Microwires. <i>Advanced Electronic Materials</i> , 2020 , 6, 1901441 | 6.4 7 |
| 50 | Direct Synthesis and Enhanced Rectification of Alloy-to-Alloy 2D Type-II MoS ₂ /SnS ₂ Heterostructures. <i>Advanced Materials</i> , 2021 , 33, e2006908 | 24 7 |
| 49 | Diamine anchored molecular junctions of oligo(phenylene ethynylene) cruciform. <i>Chinese Chemical Letters</i> , 2018 , 29, 271-275 | 8.1 6 |
| 48 | Intrinsic Linear Dichroism of Organic Single Crystals toward High-Performance Polarization-Sensitive Photodetectors. <i>Advanced Materials</i> , 2021 , e2105665 | 24 6 |

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| 47 | Polarizer-free polarimetric image sensor through anisotropic two-dimensional GeSe. <i>Science China Materials</i> , 2021 , 64, 1230-1237 | 7.1 | 6 |
| 46 | Short-Wave Near-Infrared Polarization Sensitive Photodetector Based on GaSb Nanowire. <i>IEEE Electron Device Letters</i> , 2021 , 42, 549-552 | 4.4 | 6 |
| 45 | Tuned polarity and enhanced optoelectronic performances of few-layer Nb _{0.125} Re _{0.875} Se ₂ flakes. <i>Applied Physics Letters</i> , 2016 , 109, 112102 | 3.4 | 6 |
| 44 | Nondegenerate P-Type In-Doped SnS ₂ Monolayer Transistor. <i>Advanced Electronic Materials</i> , 2021 , 7, 2001168 | 6.4 | 6 |
| 43 | Multifunctional Photodetectors Based on Nanolayered Black Phosphorus/SnS _{0.5} Se _{1.5} Heterostructures. <i>ACS Applied Nano Materials</i> , 2019 , 2, 3548-3555 | 5.6 | 5 |
| 42 | Preparing two-dimensional crystalline conjugated polymer films by synergetic polymerization and self-assembly at air/water interface. <i>Polymer Chemistry</i> , 2020 , 11, 1572-1579 | 4.9 | 5 |
| 41 | Recent progress in polarization-sensitive photodetectors based on low-dimensional semiconductors. <i>Wuli Xuebao/Acta Physica Sinica</i> , 2019 , 68, 163201 | 0.6 | 5 |
| 40 | Birefringence and Dichroism in Quasi-1D Transition Metal Trichalcogenides: Direct Experimental Investigation. <i>Small</i> , 2021 , 17, e2100457 | 11 | 5 |
| 39 | Application of transition metal dichalcogenides in mid-infrared fiber laser. <i>Nano Select</i> , 2021 , 2, 37-46 | 3.1 | 5 |
| 38 | Tunable Alloying Improved Wide Spectrum UV-Vis-NIR and Polarization-Sensitive Photodetector Based on Sb ₂ Se ₃ Nanowires. <i>IEEE Transactions on Electron Devices</i> , 2021 , 68, 3887-3893 | 2.9 | 5 |
| 37 | A ternary SnSSe alloy for flexible broadband photodetectors.. <i>RSC Advances</i> , 2019 , 9, 14352-14359 | 3.7 | 4 |
| 36 | Effect of the thickness of Bi ₂ Se ₃ sheets on the morphologies of Bi ₂ Se ₃ /nS nanocomposites and improved photoresponsive characteristic. <i>Journal of Materials Science: Materials in Electronics</i> , 2013 , 24, 4197-4203 | 2.1 | 4 |
| 35 | Synthesis and Properties of Heteroacenes Containing Pyrrole and Thiazine Rings as Promising n-Type Organic Semiconductor Candidates. <i>Chinese Journal of Chemistry</i> , 2009 , 27, 846-849 | 4.9 | 4 |
| 34 | Gate-controlled ambipolar transport in b-AsP crystals and their VIS-NIR photodetection. <i>Nanoscale</i> , 2021 , 13, 10579-10586 | 7.7 | 4 |
| 33 | Influence of solid-state electrolyte on 2D SnS ₂ field effect transistors. <i>Materials Research Express</i> , 2019 , 6, 086320 | 1.7 | 3 |
| 32 | Excitons in two-dimensional van der Waals heterostructures. <i>Journal Physics D: Applied Physics</i> , 2021 , 54, 053001 | 3 | 3 |
| 31 | When graphene meets white graphene - recent advances in the construction of graphene and h-BN heterostructures. <i>Nanoscale</i> , 2021 , 13, 13174-13194 | 7.7 | 3 |
| 30 | Band-Like Charge Transport in Small-Molecule Thin Film toward High-Performance Organic Phototransistors at Low Temperature. <i>Advanced Optical Materials</i> , 2022 , 10, 2102484 | 8.1 | 3 |

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| 29 | Metal Chalcogenides: Versatile Crystal Structures and (Opto)electronic Applications of the 2D Metal Mono-, Di-, and Tri-Chalcogenide Nanosheets (Adv. Funct. Mater. 24/2019). <i>Advanced Functional Materials</i> , 2019 , 29, 1970161 | 15.6 | 2 |
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